NSN 5962-01-177-9183

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View Online at https://aerobasegroup.com/nsn/5962-01-177-9183 **Body Length:** 0.700 inches **Body Width:** 0.700 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Metal **Inclosure Configuration:** Beam chip **Output Logic Form:** Transistor-transistor logic **Current Rating Per Characteristic:** 91.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 6.1 volts power source **Memory Device Type:** Pal **Precious Material And Location:** Case and terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 64 beam lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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